

# 1N/FDLL 914/A/B / 916/A/B / 4148 / 4448





LL-34
THE PLACEMENT OF THE EXPANSION GAP
HAS NO RELATIONSHIP TO THE LOCATION
OF THE CATHODE TERMINAL

•			
COLOR BAND MARKING			
DEVICE	1ST BAND	2ND BAND	
FDLL914	BLACK	BROWN	
FDLL914A	BLACK	GRAY	
FDLL914B	BROWN	BLACK	
FDLL916	BLACK	RED	
FDLL916A	BLACK	WHITE	
FDLL916B	BROWN	BROWN	
FDLL4148	BLACK	BROWN	
FDLL4448	BROWN	BLACK	

# **Small Signal Diode**

**Absolute Maximum Ratings\*** 

T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{RRM}$	Maximum Repetitive Reverse Voltage	100	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	200	mA
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 4.0	A A
T <sub>stg</sub>	Storage Temperature Range	-65 to +200	°C
T <sub>J</sub>	Operating Junction Temperature	175	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES

### **Thermal Characteristics**

Symbol	Characteristic	Max 1N/FDLL 914/A/B / 4148 / 4448	Units
P <sub>D</sub>	Power Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W

<sup>1)</sup> These ratings are based on a maximum junction temperature of 200 degrees C.

<sup>2)</sup> These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## **Small Signal Diode**

(continued)

### Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
$V_R$	Breakdown Voltage	$I_R = 100  \mu A$	100		V
		$I_R = 5.0  \mu A$	75		V
V <sub>F</sub>	Forward Voltage 1N914B/4448	$I_{\rm F} = 5.0  \text{mA}$	620	720	mV
	1N916B	$I_F = 5.0 \text{ mA}$	630	730	mV
	1N914/916/4148	$I_F = 10 \text{ mA}$		1.0	V
	1N914A/916A	$I_F = 20 \text{ mA}$		1.0	V
	1N916B	$I_F = 20 \text{ mA}$		1.0	V
	1N914B/4448	$I_F = 100 \text{ mA}$		1.0	V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 20 V		25	nA
		$V_R = 20 \text{ V}, T_A = 150^{\circ}\text{C}$		50	μΑ
		$V_R = 75 \text{ V}$		5.0	μΑ
C <sub>T</sub>	Total Capacitance				
	1N916A/B/4448	$V_R = 0$ , $f = 1.0 \text{ MHz}$		2.0	pF
	1N914A/B/4148	$V_R = 0$ , $f = 1.0 \text{ MHz}$		4.0	pF
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V } (60\text{mA}),$		4.0	ns
		$I_{rr} = 1.0 \text{ mA}, R_{L} = 100\Omega$			

### **Typical Characteristics**

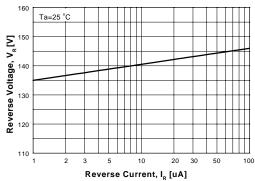
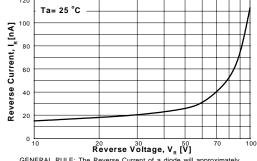


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100 uA



GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

Figure 2. Reverse Current vs Reverse Voltage

IR - 10 to 100 V

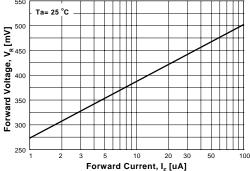


Figure 3. Forward Voltage vs Forward Current VF - 1 to 100 uA

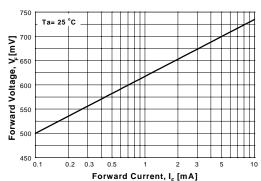


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

### **Small Signal Diode**

(continued)

# Typical Characteristics (continued)

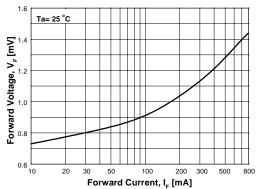
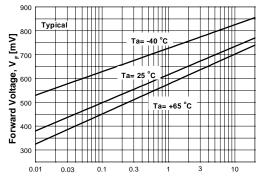


Figure 5. Forward Voltage vs Forward Current VF - 10 to 800 mA



Forward Current, I<sub>F</sub> [mA]
Figure 6. Forward Voltage
vs Ambient Temperature
VF - 0.01 - 20 mA (-40 to +65 Deg C)

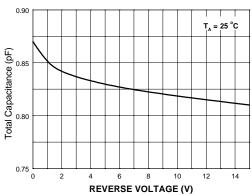


Figure 7. Total Capacitance

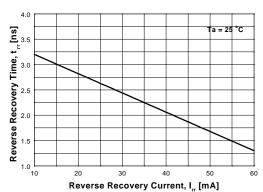


Figure 8. Reverse Recovery Time vs Reverse Recovery Current

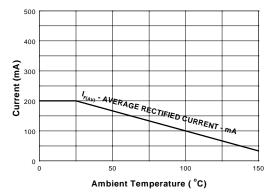


Figure 9. Average Rectified Current ( $I_{F(AV)}$ ) versus Ambient Temperature ( $T_{A}$ )

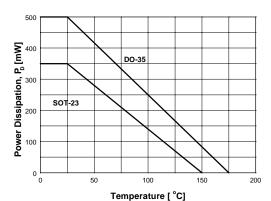


Figure 10. Power Derating Curve

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